#### TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VCXH162373FT

#### Low-Voltage 16-Bit D-Type Latch with Bushold

The TC74VCXH162373FT is a high-performance CMOS 16-bit D-type latch. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This 16-bit D-type latch is controlled by a latch enable input (LE) and an output enable input ( $\overline{OE}$ ) which are common to each byte. It can be used as two 8-bit latches or one 16-bit latch. When the  $\overline{OE}$  input is high, the outputs are in a high-impedance state.

The 26- $\Omega$  series resistor helps reducing output overshoot and undershoot without external resistor.

The D data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

All inputs are equipped with protection circuits against static discharge.

#### Features

- 26- $\Omega$  series resistors on outputs
- Low-voltage operation:  $V_{CC} = 1.8$  to 3.6 V
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- High-speed operation: t<sub>pd</sub> = 3.3 ns (max) (V<sub>CC</sub> = 3.0 to 3.6 V)
  - :  $t_{pd} = 4.5 \text{ ns} (max) (V_{CC} = 2.3 \text{ to } 2.7 \text{ V})$
  - :  $t_{pd} = 5.8 \text{ ns} (\text{max}) (V_{CC} = 1.8 \text{ V})$
- Output current:  $I_{OH}/I_{OL} = \pm 12 \text{ mA} \text{ (min)} (V_{CC} = 3.0 \text{ V})$

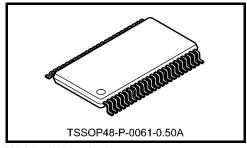
 $: I_{OH}/I_{OL} = \pm 8 \text{ mA} \text{ (min)} (V_{CC} = 2.3 \text{ V})$ 

 $: I_{OH}/I_{OL} = \pm 4 \text{ mA (min)} (V_{CC} = 1.8 \text{ V})$ 

- Latch-up performance: -300 mA
- ESD performance: Machine model  $\geq \pm 200 \text{ V}$

Human body model ≥ ±2000 V

- Package: TSSOP
- 3.6-V tolerant function and power-down protection control inputs and outputs



Weight: 0.25 g (typ.)

#### Pin Assignment (top view)

			1	
10E	1	$\bigcirc$	48	1LE
1Q1	2		47	1D1
1Q2	3		46	1D2
GND	4		45	GND
1Q3	5		44	1D3
1Q4	6		43	1D4
V <sub>CC</sub>	7		42	V <sub>CC</sub>
1Q5	8		41	1D5
1Q6	9		40	1D6
GND	10		39	GND
1Q7	11		38	1D7
1Q8	12		37	1D8
2Q1	13		36	2D1
2Q2	14		35	2D2
GND	15		34	GND
2Q3	16		33	2D3
2Q4	17		32	2D4
V <sub>CC</sub>	18		31	V <sub>CC</sub>
2Q5	19		30	2D5
2Q6	20		29	2D6
GND	21		28	GND
2Q7	22		27	2D7
2Q8	23		26	2D8
$2\overline{OE}$	24		25	2LE
		L	J	

#### IEC Logic Symbol

10E	1EN		
111	C3		
20E	2EN		
2LE <u>25</u>	C4		
1D1 <u>47</u>	3D 1 🗸	7 2	- 1Q1
1D2 <u>46</u>	· · · · · · · · · · · · · · · · · · ·	3	1Q2
1D3 <u>44</u>		5	1Q3
$1D4 - \frac{43}{3}$		6	- 1Q4
1D4 - 41		8	· 1Q5
1D5 <u>40</u>		9	· 1Q5
1D0 <u>38</u>		11	· 1Q7
1D7 1D8 <u>37</u>		12	- 1Q8
$2D1 - \frac{36}{36}$	4D 2 🗸	7 13	· 2Q1
2D2 <u>35</u>	40 2 0	14	2Q2
2D2 <u>33</u>		16	2Q3
2D0 - 32		17	2Q4
2D4 30		19	2Q5
2D5 2D6 <u>29</u>		20	- 2Q6
2D0 - 27	<u> </u>	22	2Q0
2D7 2D826	<u> </u>	23	- 2Q8
200	1		200

## <u>TOSHIBA</u>

#### **Truth Table**

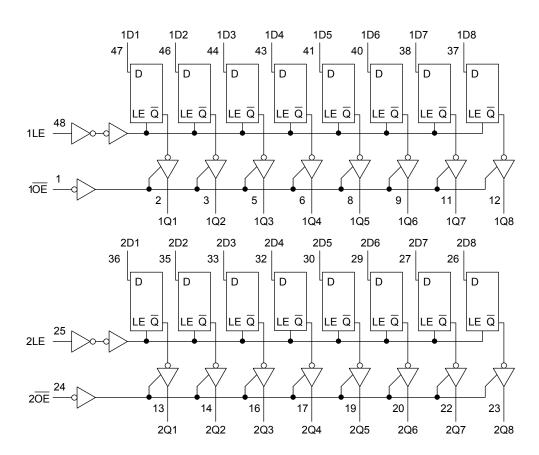
	Outputs		
1 <del>0E</del>	1LE	1D1-1D8	1Q1-1Q8
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

	Outputs		
20E	2LE	2D1-2D8	2Q1-2Q8
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	н	Н

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

#### System Diagram



#### Absolute Maximum Ratings (Note 1)

Characteristics		Symbol	Rating	Unit	
Power supply voltage		V <sub>CC</sub>	-0.5 to 4.6	V	
DC input voltage	( <del>OE</del> , LE)	V <sub>IN</sub>	–0.5 to 4.6	V	
DC input voltage	(An)	V IN	–0.5 to V <sub>CC</sub> + 0.5	v	
			-0.5 to 4.6		
DC output voltage		Vout	(Note 2)	V	
Do output voltage			-0.5 to V <sub>CC</sub> + 0.5	v	
			(Note 3)		
Input diode current		I <sub>IK</sub>	-50	mA	
Output diode current		I <sub>OK</sub>	±50 (Note 4)	mA	
Output current	Output current		±50	mA	
Power dissipation		PD	400	mW	
DC V <sub>CC</sub> /ground current	t per supply pin	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA	
Storage temperature		T <sub>stg</sub>	–65 to 150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: OFF state
- Note 3: High or low state. IOUT absolute maximum rating must be observed.
- Note 4:  $V_{OUT} < GND, V_{OUT} > V_{CC}$

#### **Operating Ranges (Note 1) (Note 2)**

Characteristics		Symbol	Rating	Unit	
Device events veltere		V <sub>CC</sub>	1.8 to 3.6	V	
Power supply voltage		VCC	1.2 to 3.6 (Note 3)	v	
Input voltage	( <del>OE</del> , LE)	V <sub>IN</sub>	-0.3 to 3.6	V	
input voltage	(An)	VIN	0 to V <sub>CC</sub>	v	
Output voltage		Vout	0 to 3.6 (Note 4)	V	
Oulput voltage		V001	0 to V <sub>CC</sub> (Note 5)	v	
			±12 (Note 6)		
Output current		I <sub>OH</sub> /I <sub>OL</sub>	±8 (Note 7)	mA	
			±4 (Note 8)		
Operating temperature		T <sub>opr</sub>	-40 to 85	°C	
Input rise and fall time		dt/dv	0 to 10 (Note 9)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

- Note 2: Floating or unused control inputs must be held high or low.
- Note 3: Data retention
- Note 4: OFF state
- Note 5: High or low state
- Note 6:  $V_{CC} = 3.0$  to 3.6 V
- Note 7:  $V_{CC} = 2.3$  to 2.7 V
- Note 8: V<sub>CC</sub> = 1.8 V
- Note 9:  $V_{IN} = 0.8$  to 2.0 V,  $V_{CC} = 3.0$  V

#### **Electrical Characteristics**

#### DC Characteristics (Ta = -40 to $85^{\circ}$ C, 2.7 V < V<sub>CC</sub> $\leq$ 3.6 V)

Characteristics		Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
lan ut velte ne	H-level	VIH			2.7 to 3.6	2.0	_	V
Input voltage	L-level	VIL			2.7 to 3.6		0.8	v
			I <sub>OH</sub> = −100 μA	2.7 to 3.6	V <sub>CC</sub> - 0.2	_		
	H-level	Vон	VIN = VIH or VIL	I <sub>OH</sub> = -6 mA	2.7	2.2		
				I <sub>OH</sub> = -8 mA	3.0	2.4		
Output voltage				$I_{OH} = -12 \text{ mA}$	3.0	2.2		v
				$I_{OL} = 100 \ \mu A$	2.7 to 3.6	_	0.2	
	L-level	V <sub>OL</sub>		$I_{OL} = 6 \text{ mA}$	2.7	_	0.4	
	L-IEVEI	VOL	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 8 \text{ mA}$	3.0	_	0.5	
				$I_{OL} = 12 \text{ mA}$	3.0	_	0.8	
Input leakage	$(\overline{OE}, LE)$	lu i	V <sub>IN</sub> = 0 to 3.6 V		2.7 to 3.6	_	±5.0	μA
current	(An)	lin	$V_{IN} = V_{CC}$ or GND		2.7 to 3.6	_	±5.0	μΑ
Bushold input minin	num drive		V <sub>IN</sub> = 0.8 V V <sub>IN</sub> = 2.0 V		3.0	75		
hold current		II (HOLD)			3.0	-75		μA
Bushold input over-	drive current			(Note 1)	3.6	_	450	
to change state		I <sub>I (OD)</sub>	(Note 2)		3.6	_	-450	μA
3-state output OFF	state current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		2.7 to 3.6		±10.0	μA
Power-off leakage of	current	I <sub>OFF</sub>	V <sub>OUT</sub> = 0 to 3.6 V		0	_	10.0	μA
	irropt		V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7 to 3.6		20.0	
Quiescent supply cu		Icc	V <sub>CC</sub> ≤ V <sub>OUT</sub> ≤ 3.6 V	(Note 3)	2.7 to 3.6	_	±20.0	μA
Increase in I <sub>CC</sub> per	input	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6		750	μA

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.

#### DC Characteristics (Ta = –40 to 85°C, 2.3 V $\leq$ V<sub>CC</sub> $\leq$ 2.7 V)

Characteris	stics	Symbol	Test C	condition	V <sub>CC</sub> (V)	Min	Max	Unit
	H-level	VIH	-		2.3 to 2.7	1.6		
Input voltage	L-level	VIL	-	_	2.3 to 2.7	_	0.7	V
				I <sub>OH</sub> = -100 μA	2.3 to 2.7	V <sub>CC</sub> - 0.2		
	H-level	Vон	VIN = VIH or VII	$I_{OH} = -4 \text{ mA}$	2.3	2.0	_	
		0.11		$I_{OH} = -6 \text{ mA}$	2.3	1.8	_	
Output voltage				I <sub>OH</sub> = -8 mA	2.3	1.7	_	V
			$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 100 μA	2.3 to 2.7	_	0.2	
	L-level	V <sub>OL</sub>		$I_{OL} = 6 \text{ mA}$	2.3	_	0.4	
				I <sub>OL</sub> = 8 mA	2.3	_	0.6	
Input leakage	( OE , LE)	lu.	V <sub>IN</sub> = 0 to 3.6 V	-	2.3 to 2.7	_	±5.0	
current	(An)	lin	$V_{IN} = V_{CC}$ or GND		2.3 to 2.7	_	±5.0	μA
Bushold input minim	um drive	1	V <sub>IN</sub> = 0.7 V		2.3	45	_	
hold current		lı (Hold)	V <sub>IN</sub> = 1.6 V		2.3	-45	_	μA
Bushold input over-c	drive current			(Note 1)	2.7	_	300	
to change state		I <sub>I (OD)</sub>	(Note 2)		2.7	_	-300	μA
3-state output OFF s	state current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		2.3 to 2.7		±10.0	μA
Power-off leakage c	urrent	I <sub>OFF</sub>	V <sub>OUT</sub> = 0 to 3.6 V		0		10.0	μA
	rrant	1	$V_{IN} = V_{CC}$ or GND		2.3 to 2.7	_	20.0	
Quiescent supply cu	irent	ICC	V <sub>CC</sub> ≤ V <sub>OUT</sub> ≤ 3.6 V	(Note 3)	2.3 to 2.7	_	±20.0	μA

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.

#### DC Characteristics (Ta = -40 to 85°C, 1.8 V $\leq$ V<sub>CC</sub> < 2.3 V)

Characteris	stics	Symbol	Test C	condition	V <sub>CC</sub> (V)	Min	Max	Unit
Input voltage	H-level	VIH	-		1.8 to 2.3	$0.7 \times V_{CC}$	_	V
input voltage	L-level	VIL	-		1.8 to 2.3		$0.2 \times V_{CC}$	v
	H-level	Vон	VIN = VIH or VIL	I <sub>OH</sub> = -100 μA	1.8	V <sub>CC</sub> - 0.2	_	
Output voltage				$I_{OH} = -4 \text{ mA}$	1.8	1.4		V
		V <sub>OL</sub>	VIN = VIH or VIL	$I_{OL} = 100 \ \mu A$	1.8		0.2	
			AIV = AIH OL AIT	$I_{OL} = 4 \text{ mA}$	1.8		0.3	
Input leakage	( <del>OE</del> )	IIN	$V_{IN} = 0$ to 3.6 V		1.8		±5.0	μA
current	(An)	NI	$V_{IN} = V_{CC}$ or GND		1.8		±5.0	μA
Bushold input minim	um drive		V <sub>IN</sub> = 0.36 V		1.8	25	_	μA
hold current		II (HOLD)	V <sub>IN</sub> = 1.26 V	1.8	-25	_	μA	
Bushold input over-c	drive current			(Note 1)	1.8		200	μA
to change state		I <sub>I (OD)</sub>		(Note 2)	1.8		-200	μA
3-state output OFF s	state current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 3.6 V		1.8		±10.0	μA
Power-off leakage c	urrent	I <sub>OFF</sub>	V <sub>OUT</sub> = 0 to 3.6 V		0	_	10.0	μA
	rront	laa	$V_{IN} = V_{CC}$ or GND		1.8	_	20.0	
Quiescent supply cu		Icc	$V_{CC} \le V_{OUT} \le 3.6 \text{ V}$	(Note 3)	1.8		±20.0	μA

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.

#### AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500 \Omega$ ) (Note 1)

Characteristics	Symbol	Symbol Test Condition		Min	Min Max	
Characteristics	Symbol			IVIIII	wax	Unit
Propagation delay time	<b>t</b>		1.8	1.5	5.8	
(D-Q)	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 2	$2.5\pm0.2$	1.0	4.5	ns
(D-Q)	чрн∟		$\textbf{3.3}\pm\textbf{0.3}$	0.8	3.3	
Propagation delay time	<b>t</b>		1.8	1.5	6.2	
(LE-Q)	t <sub>pLH</sub>	Figure 1, Figure 2	$2.5\pm0.2$	1.0	4.9	ns
	tpHL		$3.3\pm 0.3$	0.8	3.6	
	<b>4</b>		1.8	1.5	7.6	
3-state output enable time	t <sub>pZL</sub>	Figure 1, Figure 3	$2.5\pm0.2$	1.0	5.4	ns
	t <sub>pZH</sub>		$3.3\pm 0.3$	0.8	3.9	
		Figure 1, Figure 3	1.8	1.5	5.3	ns
3-state output disable time	t <sub>pLZ</sub>		$2.5\pm0.2$	1.0	4.4	
	t <sub>pHZ</sub>		$3.3\pm 0.3$	0.8	4.0	
		Figure 1, Figure 2	1.8	3.0	_	
Minimum pulse width	t <sub>w (H)</sub>		$2.5\pm0.2$	1.5		ns
(LE)			$3.3\pm 0.3$	1.5		
			1.8	2.5		
Minimum set-up time	ts	Figure 1, Figure 2	$2.5\pm0.2$	1.5	_	ns
			$3.3\pm 0.3$	1.5		
			1.8	1.0		
Minimum hold time	t <sub>h</sub>	Figure 1, Figure 2	$2.5\pm0.2$	1.0		ns
			$3.3\pm 0.3$	1.0	_	
			1.8	_	0.5	
Output to output skew	t <sub>osLH</sub>	(Note 2)	$2.5\pm0.2$	_	0.5	ns
	t <sub>osHL</sub>		$3.3\pm 0.3$	_	0.5	

Note 1: For  $C_L = 50 \text{ pF}$ , add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design.  $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$ 

#### Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0 \text{ ns}$ , $C_L = 30 \text{ pF}$ )

Characteristics	Symbol	Test Condition			Тур.	Unit
Characteristics	Symbol			$V_{CC}(V)$	тур.	Unit
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note)	1.8	0.15	
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note)	2.5	0.25	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	0.35	
	V <sub>OLV</sub>	$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note)	1.8	-0.15	v
Quiet output minimum dynamic V <sub>OI</sub>		$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note)	2.5	-0.25	
, 02		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	-0.35	
	V <sub>OHV</sub>	$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note)	1.8	1.55	
Quiet output minimum dynamic V <sub>OH</sub>		$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note)	2.5	2.05	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	2.65	

Note: Parameter guaranteed by design.

#### **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	_	Тур.	Unit
			V <sub>CC</sub> (V)		
Input capacitance	C <sub>IN</sub>	—	1.8, 2.5, 3.3	6	pF
Output capacitance	CO	_	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz (Note	) 1.8, 2.5, 3.3	20	pF

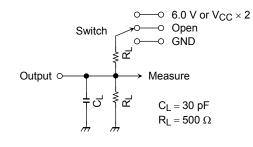
Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16$  (per bit)

### TOSHIBA

#### **AC Test Circuit**



Parameter	Switch		
t <sub>pLH</sub> , t <sub>pHL</sub>	Open		
t <sub>pLZ</sub> , t <sub>pZL</sub>			
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND		

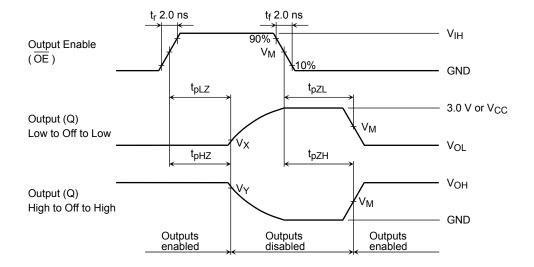


#### t<sub>f</sub> 2.0 ns t<sub>r</sub> 2.0 ns -{\ \} - VIH 90% Input VM VM (LE) 10% GND t<sub>f</sub> 2.0 ns t<sub>r</sub> 2.0 ns t<sub>w</sub> (H) ς۶- $\mathsf{V}_{\mathsf{IH}}$ 90% Input $V_{\mathsf{M}}$ $V_{\mathsf{M}}$ (D) 10% -55 GND t<sub>s</sub> (H) t<sub>h</sub> (H) t<sub>s</sub> (L) t<sub>h</sub> (L) ς۶- $V_{OH}$ Output VM $V_{\mathsf{M}}$ (Q) - V<sub>OL</sub> -55 t<sub>pLH</sub> t<sub>pHL</sub> t<sub>pHL</sub> t<sub>pLH</sub>

Figure 2  $t_{pLH}, t_{pHL}, t_w, t_s, t_h$ 

#### AC Waveform

### TOSHIBA



Symbol	V <sub>CC</sub>				
Symbol	$3.3\pm0.3~V$	$2.5\pm0.2~\text{V}$	1.8 V		
VIH	2.7 V	V <sub>CC</sub>	V <sub>CC</sub>		
VM	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub> /2		
VX	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.15 V	V <sub>OL</sub> + 0.15 V		
VY	V <sub>OH</sub> – 0.3 V	V <sub>OH</sub> – 0.15 V	V <sub>OH</sub> – 0.15 V		

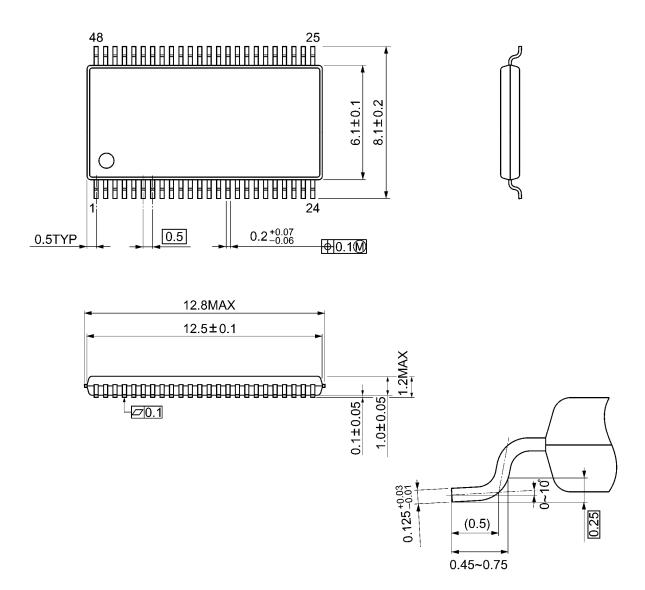
### Figure 3 $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$



#### Package Dimensions

TSSOP48-P-0061-0.50A

Unit: mm



Weight: 0.25 g (typ.)

#### **RESTRICTIONS ON PRODUCT USE**

- Toshiba Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, devices related to electric power, and equipment used in finance-related fields. IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your TOSHIBA sales representative.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
  applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without
  limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile
  technology products (mass destruction weapons). Product and related software and technology may be controlled under the
  applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the
  U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited
  except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.